

High efficiency ultrafast diode

Main product characteristics

$I_{F(AV)}$	2 x 15A
V_{RRM}	200 V
$T_j(max)$	175° C
$V_F (typ)$	0.75 V
$t_{rr} (typ)$	17 ns

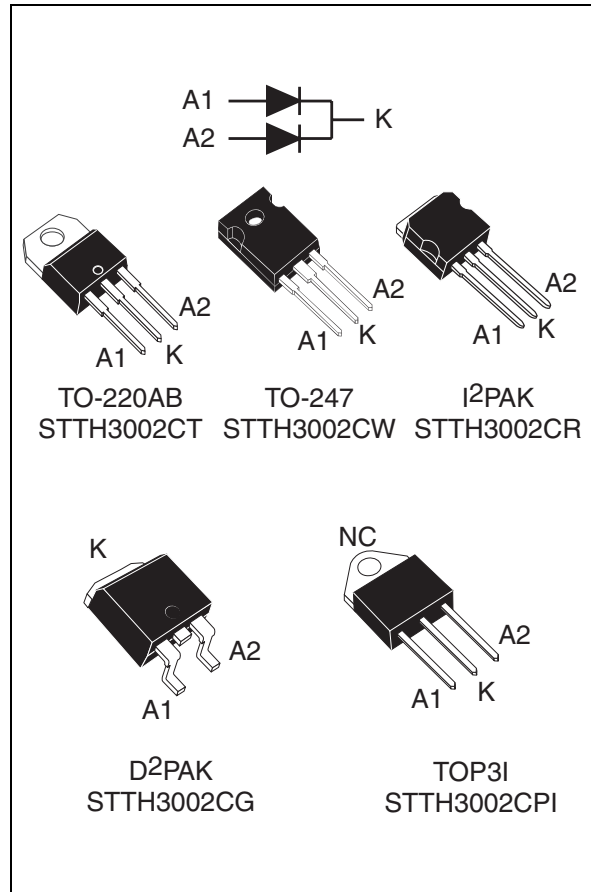
Features and benefits

- Suited for SMPS
- Low losses
- Low forward and reverse recovery times
- High surge current capability
- High junction temperature
- Insulated version TOP3I:
 - Insulated voltage: 2500 V_{rms}
 - Capacitance 12 pF

Description

Dual center tab rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in TO-220AB, TO-247, I²PAK, D²PAK, and TOP3I, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection



Order codes

Part Number	Marking
STTH3002CT	STTH3002C
STTH3002CW	STTH3002C
STTH3002CR	STTH3002C
STTH3002CG	STTH3002C
STTH3002CG-TR	STTH3002C
STTH3002CPI	STTH3002C

1 Characteristics

Table 1. Absolute ratings (limiting values at $T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			200	V
I _{F(RMS)}	RMS forward current			50	A
I _{F(AV)}	Average forward current, δ = 0.5	TO-220AB, TO-247, I ² PAK, D ² PAK	Per diode T _c = 150° C	15	A
			Per device T _c = 145° C	30	
		TOP3I	Per diode T _c = 125° C	15	
			Per device T _c = 105° C	30	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sinusoidal		180	A
T _{stg}	Storage temperature range			-65 to +175	° C
T _j	Maximum operating junction temperature			175	° C

Table 2. Thermal parameters

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AB, TO-247, I ² PAK, D ² PAK	Per diode	1.5	$^\circ\text{C/W}$
			Total	1.0	
		TOP3I	Per diode	3.5	
			Total	2.3	
$R_{th(c)}$	Coupling	TO-220AB, TO-247, I ² PAK, D ² PAK		0.5	
		TOP3I		1.1	

When the two diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ \text{C}$	$V_R = V_{RRM}$			20	μA
		$T_j = 125^\circ \text{C}$			10	125	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ \text{C}$	$I_F = 15 \text{ A}$			1.05	V
			$I_F = 30 \text{ A}$			1.18	
		$T_j = 150^\circ \text{C}$	$I_F = 15 \text{ A}$		0.75	0.84	
			$I_F = 30 \text{ A}$			0.99	

1. Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2 \%$

2. Pulse test: $t_p = 380 \mu\text{s}$, $\delta < 2 \%$

To evaluate the conduction losses use the following equation:

$$P = 0.69 \times I_{F(AV)} + 0.01 I_{F(RMS)}^2$$

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 1 \text{ A}$, $dI_F/dt = 200 \text{ A}/\mu\text{s}$, $V_R = 30 \text{ V}$, $T_j = 25^\circ \text{C}$		17	22	ns
I_{RM}	Reverse recovery current	$I_F = 15 \text{ A}$, $dI_F/dt = 200 \text{ A}/\mu\text{s}$, $V_R = 160 \text{ V}$, $T_j = 125^\circ \text{C}$		6	7.8	A
t_{fr}	Forward recovery time	$I_F = 15 \text{ A}$, $dI_F/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$, $T_j = 25^\circ \text{C}$			110	ns
V_{FP}	Forward recovery voltage	$I_F = 15 \text{ A}$, $dI_F/dt = 200 \text{ A}/\mu\text{s}$, $T_j = 25^\circ \text{C}$		2.5		V

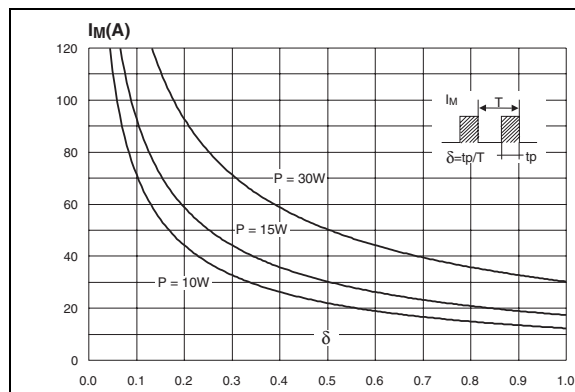
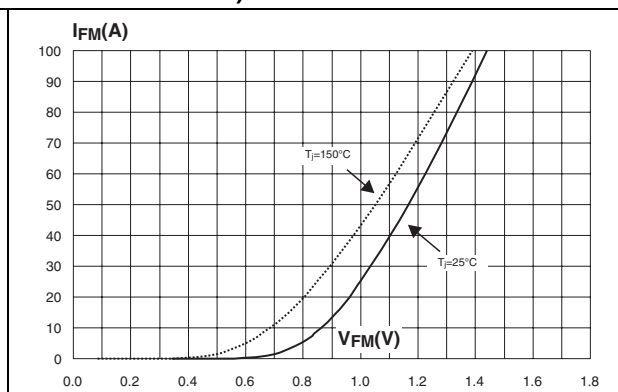
Figure 1. Peak current versus duty cycle (per diode)**Figure 2. Forward voltage drop versus forward current (typical values, per diode)**

Figure 3. Forward voltage drop versus forward current (maximum values, per diode)

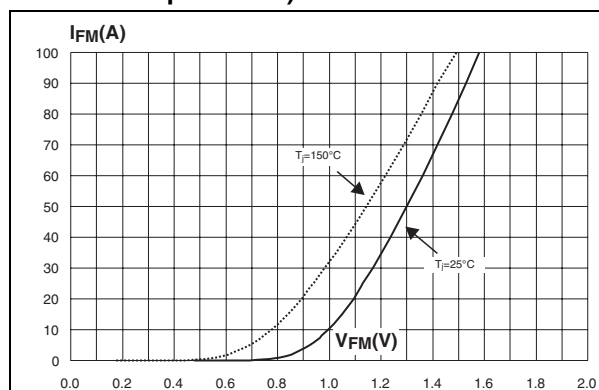


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

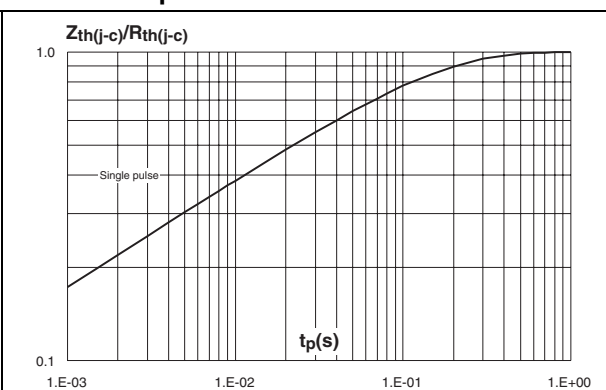


Figure 5. Junction capacitance versus reverse applied voltage (typical values, per diode)

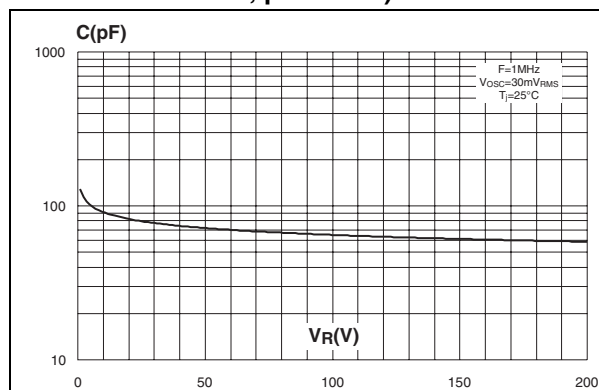


Figure 6. Reverse recovery charges versus dl_F/dt (typical values, per diode)

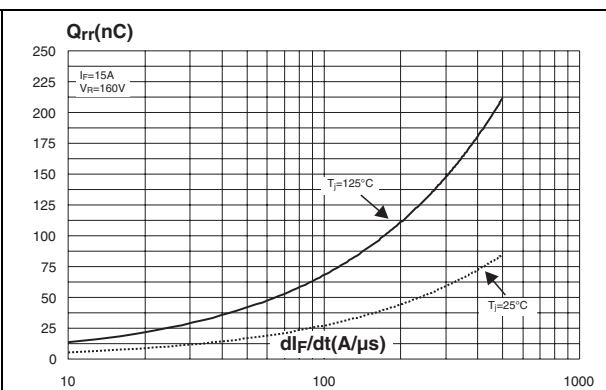


Figure 7. Reverse recovery time versus dl_F/dt (typical values, per diode)

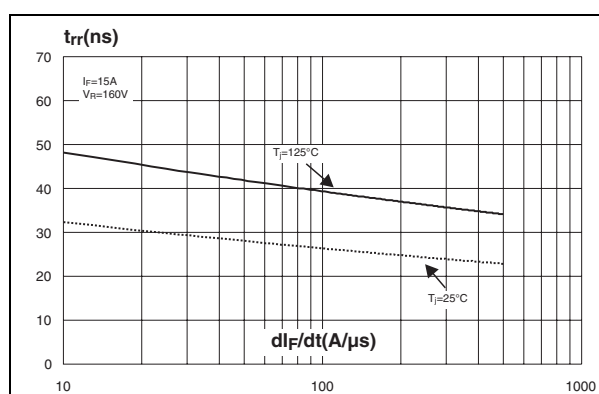


Figure 8. Peak reverse recovery current versus dl_F/dt (typical values, per diode)

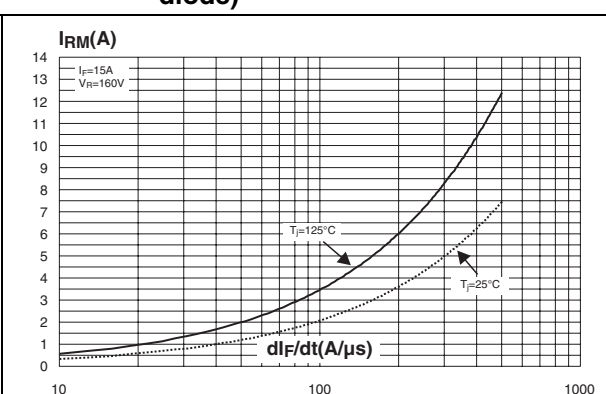


Figure 9. Dynamic parameters versus junction temperature

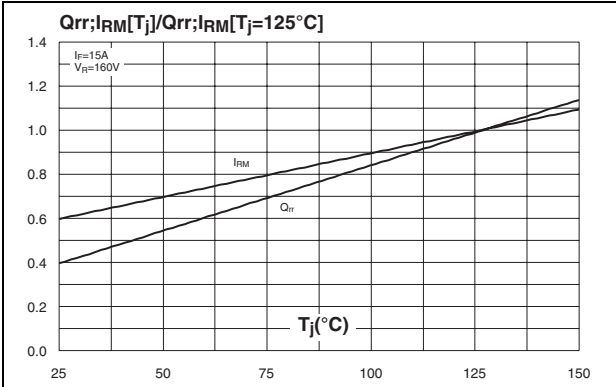
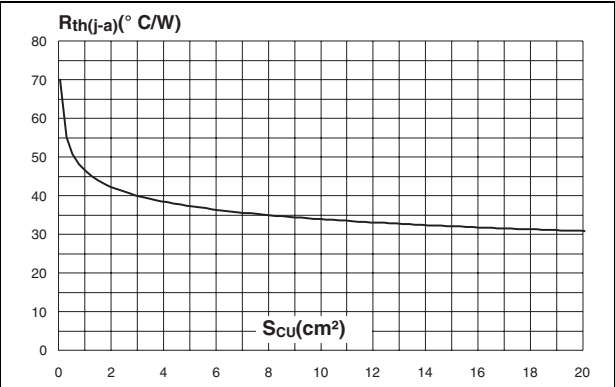
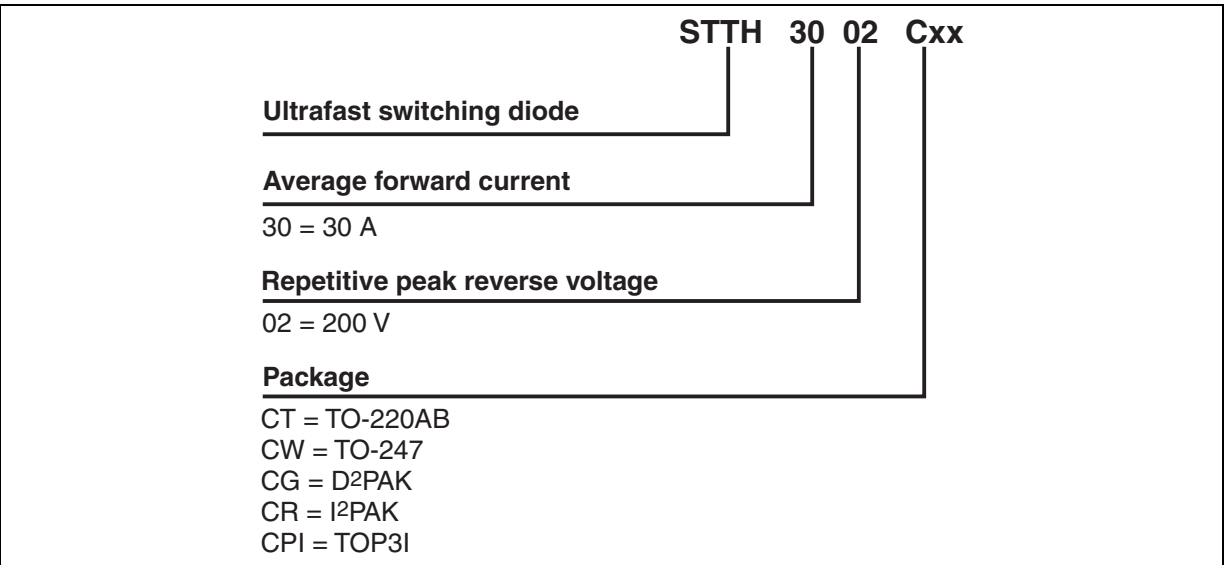


Figure 10. Thermal resistance junction to ambient versus copper surface under each tab (Epoxy printed circuit board FR4, $e_{\text{CU}} = 35\text{ }\mu\text{m}$) for D²PAK



2 Ordering information scheme



3 Package information

Epoxy meets UL94, V0

Cooling method: by conduction (C)

Recommended torque value: 0.8 Nm

Maximum torque value: 1.0 Nm

Table 5. TO-220AB Dimensions

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ	Max.	Min.	Typ	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

Table 6. TO-247 Dimensions

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ	Max.	Min.	Typ	Max.
A	4.85		5.15	0.191		0.203
D	2.20		2.60	0.086		0.102
E	0.40		0.80	0.015		0.031
F	1.00		1.40	0.039		0.055
F1		3.00			0.118	
F2		2.00			0.078	
F3	2.00		2.40	0.078		0.094
F4	3.00		3.40	0.118		0.133
G		10.90			0.429	
H	15.45		15.75	0.608		0.620
L	19.85		20.15	0.781		0.793
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
L3	14.20		14.80	0.559		0.582
L4		34.60			1.362	
L5		5.50			0.216	
M	2.00		3.00	0.078		0.118
V		5°			5°	
V2		60°			60°	
Dia.	3.55		3.65	0.139		0.143

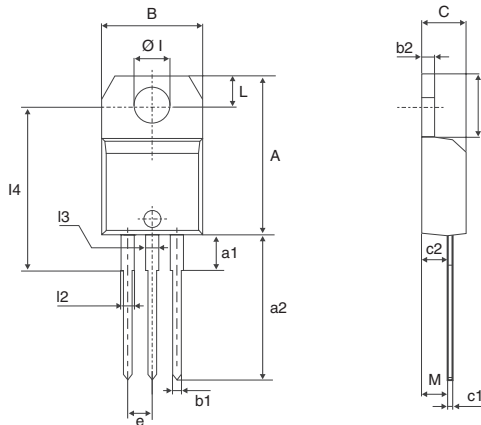


Table 7. I²PAK Dimensions

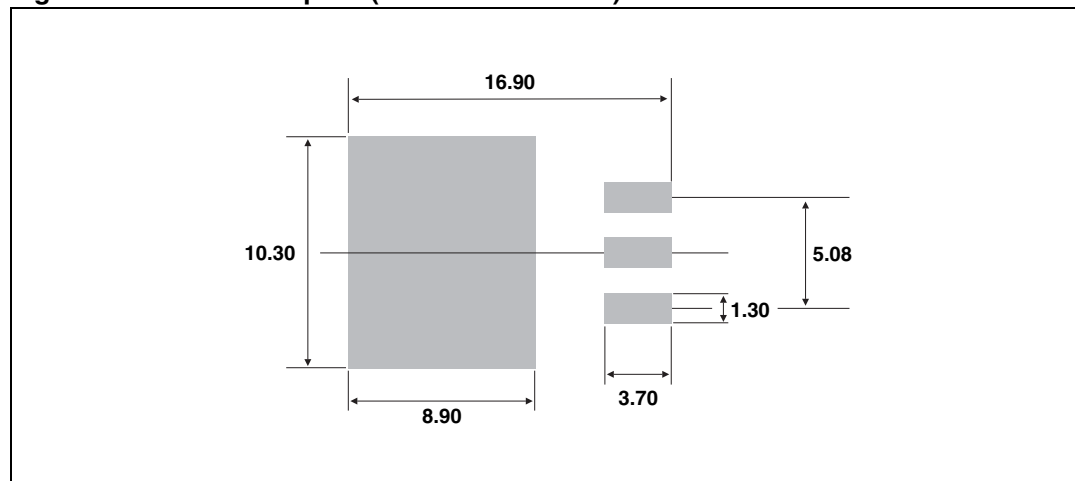
REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10	10.40	0.394	0.409
L	13	14	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055

Table 8. TOP3I dimensions

REF	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	1.45	1.55	0.057	0.061
C	14.35	15.60	0.565	0.614
D	0.5	0.7	0.020	0.028
E	2.7	2.9	0.106	0.114
F	15.8	16.5	0.622	0.650
G	20.4	21.1	0.815	0.831
H	15.1	15.5	0.594	0.610
J	5.4	5.65	0.213	0.222
K	3.4	3.65	0.134	0.144
ØL	4.08	4.17	0.161	0.164
P	1.20	1.40	0.047	0.055
R	4.60 Typ.		0.181 Typ.	

Table 9. D²PAK dimensions

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

Figure 11. D²PAK footprint (dimensions in mm)

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH3002CT	STTH3002C	TO-220AB	2.23 g	50	Tube
STTH3002CW	STTH3002C	TO-247	4.46 g	30	Tube
STTH3002CR	STTH3002C	I ² PAK	1.49 g	50	Tube
STTH3002CG	STTH3002C	D ² PAK	1.48 g	50	Tube
STTH3002CG-TR	STTH3002C	D ² PAK	1.48 g	1000	Tape and reel
STTH3002CPI	STTH3002C	TOP3I	4.7 g	30	Tube

5 Revision history

Date	Revision	Description of Changes
Feb-2004	1	First issue
05-Apr-2006	2	Reformatted to current template. Package TOP3I added.

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